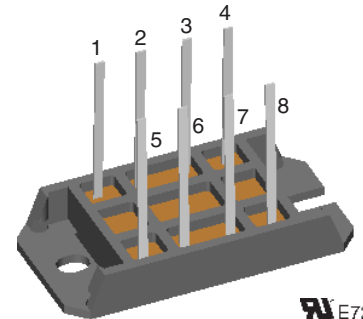
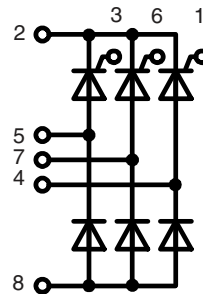


# Three Phase Half Controlled Rectifier Bridge

$I_{dAVM} = 43 \text{ A}$   
 $V_{RRM} = 1200\text{-}1600 \text{ V}$

$V_{RSM}$ $V_{DSM}$ V	$V_{RRM}$ $V_{DRM}$ V	Type
1300	1200	VVZ 40-12io1
1500	1400	VVZ 40-14io1
1700	1600	VVZ 40-16io1



Symbol	Conditions	Maximum Ratings
$I_{dAV}$	$T_K = 100^\circ\text{C}$ ; module	34 A
$I_{dAVM}$	module	43 A
$I_{FRMS}, I_{TRMS}$	per leg	25 A
$I_{FSM}, I_{TSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine 320 A $t = 8.3 \text{ ms}$ (60 Hz), sine 340 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine 290 A $t = 8.3 \text{ ms}$ (60 Hz), sine 310 A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine 510 $\text{A}^2\text{s}$ $t = 8.3 \text{ ms}$ (60 Hz), sine 485 $\text{A}^2\text{s}$
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine 420 $\text{A}^2\text{s}$ $t = 8.3 \text{ ms}$ (60 Hz), sine 400 $\text{A}^2\text{s}$
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $f = 400 \text{ Hz}$ , $t_p = 200 \mu\text{s}$ $V_D = 2/3 V_{DRM}$ $I_G = 0.3 \text{ A}$ , $di_G/dt = 0.3 \text{ A}/\mu\text{s}$	repetitive, $I_T = 50 \text{ A}$ 150 $\text{A}/\mu\text{s}$ non repetitive, $I_T = 1/3 \cdot I_{dAV}$ 500 $\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$ ; $V_{DR} = 2/3 V_{DRM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	1000 $\text{V}/\mu\text{s}$
$V_{RGM}$		10 V
$P_{GM}$	$T_{VJ} = T_{VJM}$ $I_T = I_{TAVM}$	$t_p = 30 \mu\text{s}$ $\leq 10$ W
		$t_p = 500 \mu\text{s}$ $\leq 5$ W
		$t_p = 10 \text{ ms}$ $\leq 1$ W
$P_{GAVM}$		0.5 W
$T_{VJ}$		-40...+125 $^\circ\text{C}$
$T_{VJM}$		125 $^\circ\text{C}$
$T_{stg}$		-40...+125 $^\circ\text{C}$
$V_{ISOL}$	50/60 Hz, RMS	$t = 1 \text{ min}$ 3000 V~ $t = 1 \text{ s}$ 3600 V~
	$I_{ISOL} \leq 1 \text{ mA}$	
$M_d$	Mounting torque	(M5) 2-2.5 Nm
		(10-32 UNF) 18-22 lb.in.
Weight	typ.	28 g

## Features

- Package with DCB ceramic base plate
- Isolation voltage 3600 V~
- Planar passivated chips
- Soldering terminals
- UL registered E 72873

## Applications

- Input rectifier for switch mode power supplies (SMPS)
- Softstart capacitor charging
- Electric drives and auxiliaries

## Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated.

Symbol	Conditions	Characteristic Values
$I_R, I_D$	$V_R = V_{RRM}; V_D = V_{DRM}$ $T_{VJ} = T_{VJM}$ $T_{VJ} = 25^\circ\text{C}$	$\leq 5$ mA $\leq 0.3$ mA
$V_F, V_T$	$I_F, I_T = 30$ A, $T_{VJ} = 25^\circ\text{C}$	$\leq 1.33$ V
$V_{T0}$	For power-loss calculations only	0.85 V
$r_T$	( $T_{VJ} = 125^\circ\text{C}$ )	15 m $\Omega$
$V_{GT}$	$V_D = 6$ V; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	$\leq 1.0$ V $\leq 1.2$ V
$I_{GT}$	$V_D = 6$ V; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	$\leq 65$ mA $\leq 80$ mA $\leq 50$ mA
$V_{GD}$	$T_{VJ} = T_{VJM};$	$\leq 0.2$ V
$I_{GD}$	$T_{VJ} = T_{VJM};$ $V_D = 2/3 V_{DRM}$ $V_D = 2/3 V_{DRM}$	$\leq 5$ mA
$I_L$	$I_G = 0.3$ A; $t_G = 30$ $\mu\text{s}$ $di_G/dt = 0.3$ A/ $\mu\text{s}$ $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	$\leq 150$ mA $\leq 200$ mA $\leq 100$ mA
$I_H$	$T_{VJ} = 25^\circ\text{C}; V_D = 6$ V; $R_{GK} = \infty$	$\leq 100$ mA
$t_{gd}$	$T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$ $I_G = 0.3$ A; $di_G/dt = 0.3$ A/ $\mu\text{s}$	$\leq 2$ $\mu\text{s}$
$t_q$	$T_{VJ} = 125^\circ\text{C}; I_T = 15$ A, $t_p = 300$ $\mu\text{s}$ , $-di/dt = 10$ A/ $\mu\text{s}$	typ. 150 $\mu\text{s}$
$Q_f$	$V_R = 100$ V, $dv/dt = 20$ V/ $\mu\text{s}$ , $V_D = 2/3 V_{DRM}$	75 $\mu\text{C}$
$R_{thJC}$	per thyristor (diode); DC current per module	1.0 K/W 0.17 K/W
$R_{thJH}$	per thyristor (diode); DC current per module	1.6 K/W 0.27 K/W
$d_s$	Creeping distance on surface	7 mm
$d_A$	Creepage distance in air	7 mm
$a$	Max. allowable acceleration	50 m/s <sup>2</sup>

**Dimensions in mm (1 mm = 0.0394")**
